Hex buffer/line driver; 3-state Rev. 6 — 28 July 2021

1. General description

The 74HC365; 74HCT365 is a hex buffer/line driver with 3-state outputs controlled by the output enable inputs (\overline{OEn}). A HIGH on \overline{OEn} causes the outputs to assume a high impedance OFF-state. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. Features and benefits

- Wide supply voltage range from 2.0 V to 6.0 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
- · Non-inverting outputs
- Input levels:
 - For 74HC365: CMOS level
 - For 74HCT365: TTL level
- ESD protection:
- HBM JESD22-A114F exceeds 2000 V
- MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

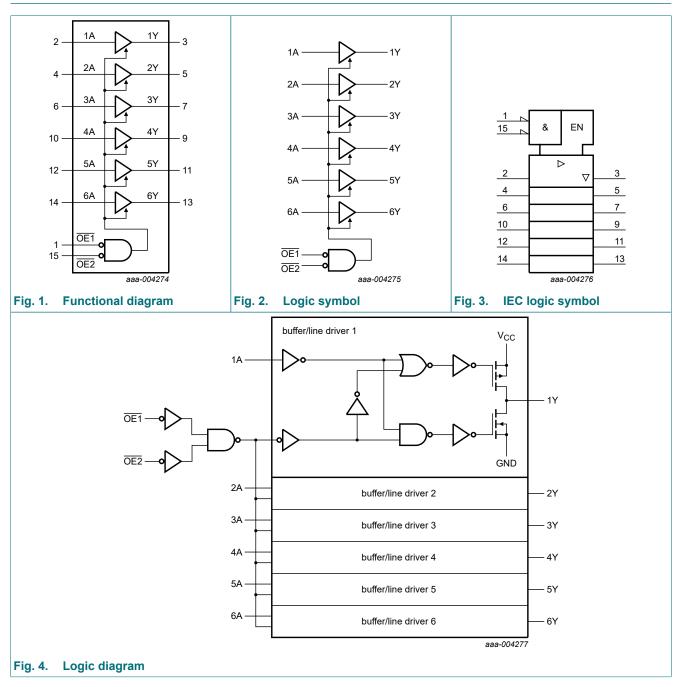
3. Ordering information

Table 1. Ordering information

74HC365D 74HCT365D	Package			
	Temperature range	Name	Description	Version
74HC365D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT365D				
74HC365PW	-40 °C to +125 °C	TSSOP16		SOT403-1
74HCT365PW			body width 4.4 mm	

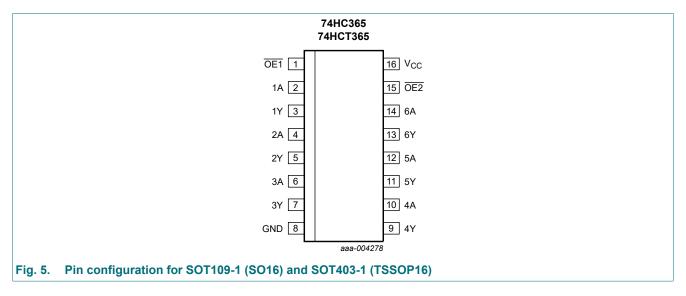
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4. Functional diagram



5. Pinning information

5.1. Pinning



5.2. Pin description

Symbol	Pin	Description
OE1	1	output enable input 1 (active LOW)
1A	2	data input 1
1Y	3	data output 1
2A	4	data input 2
2Y	5	data output 2
3A	6	data input 3
3Y	7	data output 3
GND	8	ground (0 V)
4Y	9	data output 4
4A	10	data input 4
5Y	11	data output 5
5A	12	data input 5
6Y	13	data output 6
6A	14	data input 6
OE2	15	output enable input 2 (active LOW)
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

		Input	Output
OE1	OE2	nA	nY
L	L	L	L
L	L	Н	Н
X	Н	Х	Z
Н	Х	Х	Z

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{\rm I} < -0.5 \text{ V or } V_{\rm I} > V_{\rm CC} + 0.5 \text{ V}$ [1]	-	±20	mA
I _{OK}	output clamping current	$V_{\rm O} < -0.5 \text{ V or } V_{\rm O} > V_{\rm CC} + 0.5 \text{ V}$ [1]	-	±20	mA
lo	output current	$V_{\rm O}$ = -0.5 V to (V _{CC} + 0.5 V)	-	±35	mA
I _{CC}	supply current		-	70	mA
I _{GND}	ground current		-70	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	[2]	-	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C.

For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions 74HC365			7	Unit			
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics 74HC365

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C		I			
VIH	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	- - 0.5 1.35 1.35 1.8 - - - - 0.1 0.1 0.1 0.1 0.1 0.1 0.1 0.1 0.1 0.1 0.1 0.1 0.1 0.26 ±0.5 8.0 - - - 0.26 ±0.1 ±0.5 8.0 - - - - - - - - - - - - - - - - - - -	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}	-	-	-	
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	V
		I _O = -6.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.48	5.81	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	0	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	0	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	0.16	0.26	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } \text{GND}; V_{CC} = 6.0 \text{ V}$	-	-	±0.5	μA
Icc	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	μA
CI	input capacitance		-	3.5	-	pF
T _{amb} = -4	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	-	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	-	-	V
		I _O = -6.0 mA; V _{CC} = 4.5 V	3.84	-	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.34	-	-	V

Hex buffer/line driver; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	-	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.33	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	-	0.33	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±1.0	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } \text{GND}; V_{CC} = 6.0 \text{ V}$	-	-	±5.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μA
T _{amb} = -4	10 °C to +125 °C	·				
VIH	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = -20 μA; V _{CC} = 2.0 V	1.9	-	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	-	-	V
		I _O = -6.0 mA; V _{CC} = 4.5 V	3.7	-	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.2	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 μA; V _{CC} = 2.0 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	-	0.1	V
		I _O = 20 μA; V _{CC} = 6.0 V	-	-	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	-	0.4	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	-	0.4	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±1.0	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH}$ or V_{IL} ; $V_{O} = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±10.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	160	μA

Table 7. Static characteristics 74HCT365

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	4.5	-	V
		I _O = -6.0 mA	3.98	4.32	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	0	0.1	V
		I _O = 6.0 mA	-	0.16	0.26	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	μA
l _{oz}	OFF-state output current	$V_{I} = V_{IH}$ or V_{IL} ; $V_{O} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.5	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	μA
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$				
		pins nA	-	100	360	μA
		pin OE1	-	100	360	μA
		pin OE2	-	90	324	μA
CI	input capacitance		-	3.5	-	pF
T _{amb} = -4	40 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
VIL	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	-	-	V
		I _O = -6.0 mA	3.84	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	-	0.1	V
		I _O = 6.0 mA	-	-	0.33	V
l _l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
l _{oz}	OFF-state output current	$V_{I} = V_{IH}$ or V_{IL} ; $V_{O} = V_{CC}$ or GND; $V_{CC} = 5.5 V$			±5.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μA
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 2.1 V$; other inputs at V_{CC} or GND; $I_O = 0 A$				
		pins nA	-	-	450	μA
		pin OE1	-	-	450	μA
		pin OE2	-	-	405	μA

Hex buffer/line driver; 3-state

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$\begin{array}{c c c c c c c c c c c c c c c c c c c $						
VIH	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
V _{OH}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	-	-	V
		I _O = -6.0 mA	3.7	-	-	V
V _{OL}	-	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
		I _O = 20 μA	-	-	0.1	V
		I _O = 6.0 mA	-	-	0.4	V
I _I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
I _{OZ}	OFF-state output current	$V_{I} = V_{IH}$ or V_{IL} ; $V_{O} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±10.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	160	μA
ΔI_{CC}	additional supply current	$V_I = V_{CC} - 2.1 V$; other inputs at V_{CC} or GND; $I_O = 0 A$				
		pins nA	-	-	490	μA
		pin OE1	-	-	490	μA
		pin OE2	-	-	441	μA

10. Dynamic characteristics

Table 8. Dynamic characteristics 74HC365

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; see test circuit Fig. 8.

Symbo	I Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} =	25 °C						
t _{pd}	propagation delay	nA to nY; see <u>Fig. 6</u>	[1]				
		V _{CC} = 2.0 V		-	30	Max 95 19 - 16 30 26 150 30 26 150 30 26 150 10 26 26 10	ns
		V _{CC} = 4.5 V		-	11		ns
		V _{CC} = 5 V; C _L = 15 pF		-	9	-	ns
		V _{CC} = 6.0 V		-	9	16	ns
t _{en}	enable time	OEn to nY; see Fig. 7	[2]				
		V _{CC} = 2.0 V		-	47	150	ns
		V _{CC} = 4.5 V		-	17	30	ns
		V _{CC} = 6.0 V		-	14	26	ns
t _{dis}	disable time	OEn to nY; see Fig. 7	[3]				
		V _{CC} = 2.0 V		-	61	150	ns
		V _{CC} = 4.5 V		-	22	30	30 ns 26 ns 150 ns 30 ns
		V _{CC} = 6.0 V		-	18	26	ns
tt	transition time	see <u>Fig. 6</u>	[4]				
		V _{CC} = 2.0 V		-	14	60	ns
		V _{CC} = 4.5 V		-	5	12	ns
		V _{CC} = 6.0 V		-	4	10	ns
C _{PD}	power dissipation capacitance	per buffer; V_I = GND to V_{CC}	[5]	-	40	-	pF

Hex buffer/line driver; 3-state

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
T _{amb} = -4	40 °C to +85 °C						
t _{pd}	propagation delay	nA to nY; see <u>Fig. 6</u>	[1]				
		V _{CC} = 2.0 V		-	-	120	ns
		V _{CC} = 4.5 V		-	-	24	ns
		V _{CC} = 6.0 V		-	-	20	ns
en	enable time	OEn to nY; see Fig. 7	[2]				
		V _{CC} = 2.0 V		-	-	190	ns
		V _{CC} = 4.5 V		-	-	38	ns
		V _{CC} = 6.0 V		-	-	33	ns
dis	disable time	OEn to nY; see Fig. 7	[3]				
		V _{CC} = 2.0 V		-	-	190	ns
		V _{CC} = 4.5 V		-	-	38	ns
		V _{CC} = 6.0 V		-	-	33	ns
t	transition time	see <u>Fig. 6</u>	[4]				
		V _{CC} = 2.0 V		-	-	75	ns
		V _{CC} = 4.5 V		-	-	15	ns
		V _{CC} = 6.0 V		-	-	13	ns
T _{amb} = -4	40 °C to +125 °C						1
pd	propagation delay	nA to nY; see <u>Fig. 6</u>	[1]				
		V _{CC} = 2.0 V		-	-	145	ns
		V _{CC} = 4.5 V		-	-	29	ns
		V _{CC} = 6.0 V		-	-	25	ns
en	enable time	OEn to nY; see Fig. 7	[2]				
		V _{CC} = 2.0 V		-	-	225	ns
		V _{CC} = 4.5 V		-	-	45	ns
		V _{CC} = 6.0 V		-	-	38	ns
dis	disable time	OEn to nY; see Fig. 7	[3]				
		V _{CC} = 2.0 V		-	-	225	ns
		V _{CC} = 4.5 V		-	-	45	ns
		V _{CC} = 6.0 V		-	-	38	ns
t	transition time	see <u>Fig. 6</u>	[4]				1
		V _{CC} = 2.0 V		-	-	90	ns
		$V_{CC} = 4.5 V$		-	-	18	ns
		V _{CC} = 6.0 V		-	-	15	ns

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] \dot{t}_{en} is the same as t_{PZH} and t_{PZL} .

[2] t_{dis} is the same as t_{PLZ} and t_{PLZ}.
[3] t_{dis} is the same as t_{PHZ} and t_{PLZ}.
[4] t_t is the same as t_{THL} and t_{TLH}.
[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW). P_D = C_{PD} x V_{CC}² x f_i x N + Σ(C_L x V_{CC}² x f_o) where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

Table 9. Dynamic characteristics 74HCT365

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; see test circuit Fig. 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	5 °C				1	1	1
t _{pd}	propagation delay	nA to nY; see <u>Fig. 6</u>	[1]				
		V _{CC} = 4.5 V		-	14	25	ns
		V _{CC} = 5 V; C _L = 15 pF		-	11	-	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see <u>Fig. 7</u>	[2]	-	18	35	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see <u>Fig. 7</u>	[3]	-	23	35	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Fig. 6</u>	[4]	-	5	12	ns
C _{PD}	power dissipation capacitance	per buffer; V_I = GND to (V_{CC} - 1.5 V)	[5]	-	40	-	pF
T _{amb} = -4	40 °C to +85 °C						
t _{pd}	propagation delay	nA to nY; V _{CC} = 4.5 V; see <u>Fig. 6</u>	[1]	-	-	31	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see <u>Fig. 7</u>	[2]	-	-	44	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see <u>Fig. 7</u>	[3]	-	-	44	ns
tt	transition time	V _{CC} = 4.5 V; see <u>Fig. 6</u>	[4]	-	-	15	ns
T _{amb} = -4	40 °C to +125 °C						
t _{pd}	propagation delay	nA to nY; V _{CC} = 4.5 V; see <u>Fig. 6</u>	[1]	-	-	38	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see <u>Fig. 7</u>	[2]	-	-	53	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see <u>Fig. 7</u>	[3]	-	-	53	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Fig. 6</u>	[4]	-	-	18	ns

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_{en} is the same as t_{PZH} and t_{PZL} .

[3] t_{dis} is the same as t_{PHZ} and $t_{\text{PLZ}}.$

[3] t_{dis} is the same as t_{PHZ} and t_{PLZ}.
[4] t_t is the same as t_{THL} and t_{TLH}.
[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW). P_D = C_{PD} x V_{CC}² x f_i x N + Σ(C_L x V_{CC}² x f_o) where: f_i = input frequency in MHz;

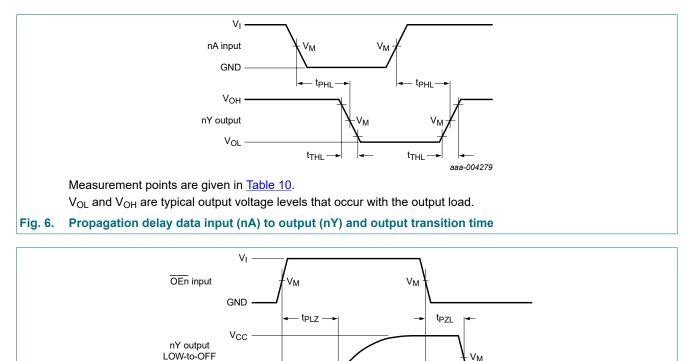
 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.



٧x

V٨

⊷ t_{PZH} –

outputs

disabled

VM

outputs

enabled

001aaf586

t_{PHZ}

outputs enabled

10.1. Waveforms and test circuit

Table 10. Measurement points

OFF-to-LOW

nY output HIGH-to-OFF

OFF-to-HIGH

Measurement points are given in Table 10.

3-state enable and disable times

VOL

VOH

GND

 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Table To. Measurement points					
Туре	Input	Output	Output		
	V _M	V _M	V _X	V _Y	
74HC365	0.5V _{CC}	0.5V _{CC}	0.1 × V _{CC}	$0.9 \times V_{CC}$	
74HCT365	1.3 V	1.3 V	0.1 × V _{CC}	$0.9 \times V_{CC}$	

Fig. 7.

Hex buffer/line driver; 3-state

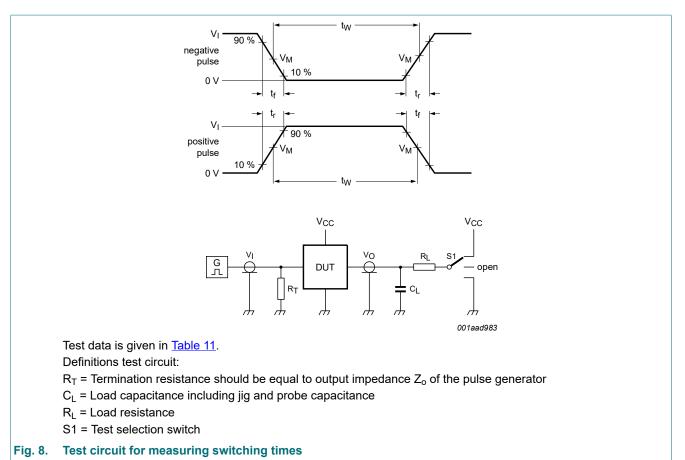


Table 11. Test data

Туре	Input		Load		S1 position		
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
74HC365	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}
74HCT365	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}

11. Package outline

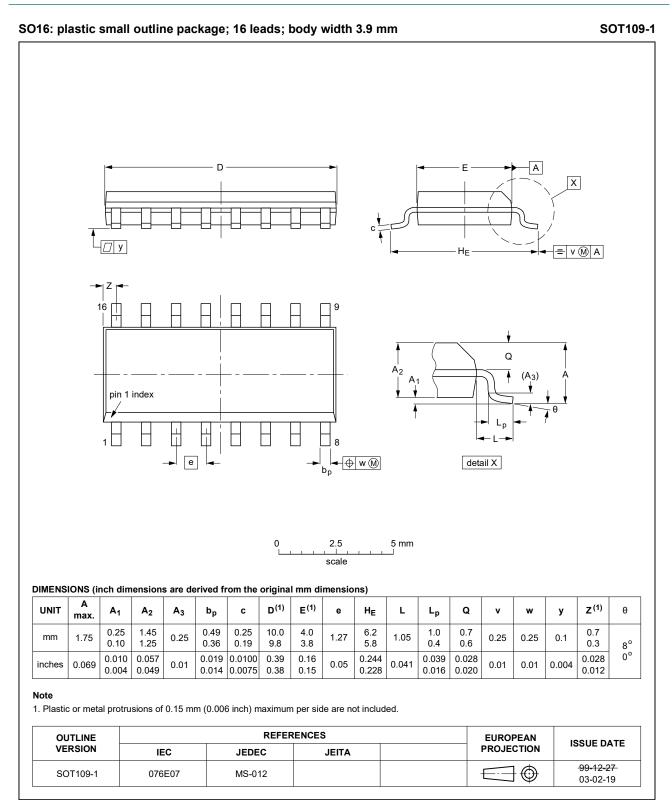


Fig. 9. Package outline SOT109-1 (SO16)

74HC_HCT365

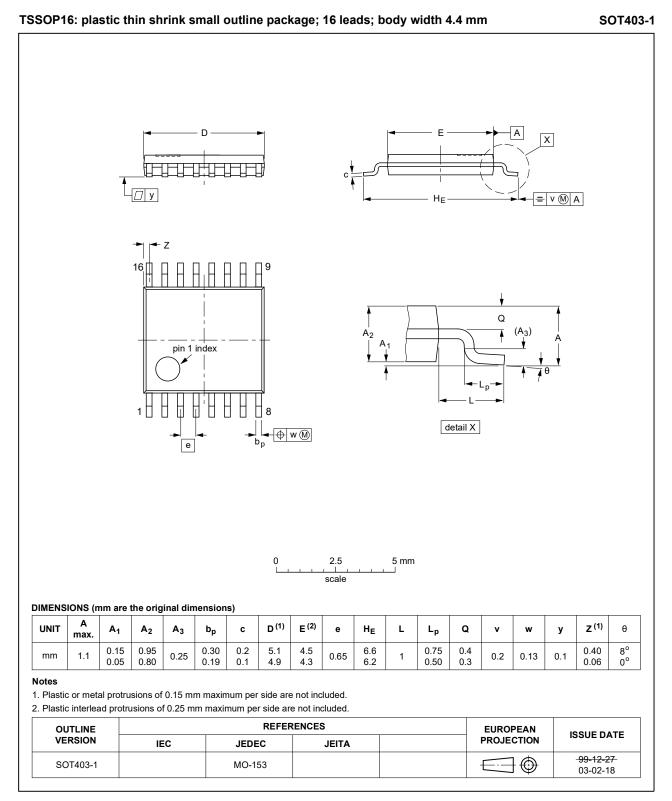


Fig. 10. Package outline SOT403-1 (TSSOP16)

⁷⁴HC_HCT365

12. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

13. Revision history

Table 13. Revision histor	y				
Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT365 v.6	20210728	Product data sheet	-	74HC_HCT365 v.5	
Modifications:	Type number 74HCT365DB (SOT338-1/SSOP16) removed.				
74HC_HCT365 v.5	20210212	Product data sheet	-	74HC_HCT365 v.4	
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. <u>Section 1</u> and <u>Section 2</u> updated. Type number 74HC365DB (SOT338-1/SSOP16) removed. <u>Section 7</u>: Derating values for P_{tot} total power dissipation updated. 				
74HC_HCT365 v.4	20160127	Product data sheet	-	74HC_HCT365 v.3	
Modifications:	Type numbers 74HC365N and 74HCT365N (SOT38-4) removed.				
74HC_HCT365 v.3	20120905	Product data sheet	-	74HC_HCT365_CNV v.2	
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. 				
74HC_HCT365_CNV v.2	19970829	Product specification	-	-	

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Hex buffer/line driver; 3-state

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